

1. Record Nr.	UNINA9910151593403321
Autore	Thornton Phil (Business writer)
Titolo	The great economists : ten economists whose thinking changed the way we live / / Phil Thornton
Pubbl/distr/stampa	Harlow, England : , : Pearson, , [2014] ©2014
ISBN	1-292-00943-8
Edizione	[1st edition]
Descrizione fisica	1 online resource (viii, 249 pages)
Disciplina	330.092/2
Soggetti	Economists Economics - History
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Note generali	Includes index.
Nota di bibliografia	Includes bibliographical references and index.
Nota di contenuto	Cover -- Contents -- Acknowledgements -- About the author -- Introduction -- Chapter 1: Adam Smith - the 'founding father' of economics -- Chapter 2: David Ricardo - from immigrant to gentleman -- Chapter 3: Karl Marx - the fallen hero? -- Chapter 4: Alfred Marshall - microeconomics arrives -- Chapter 5: John Maynard Keynes - the rise, fall, rise ... and fall -- Chapter 6: Friedrich Hayek - the archetypal libertarian -- Chapter 7: Milton Friedman - father of monetarism -- Chapter 8: Paul Samuelson - the neoclassical synthesist -- Chapter 9: Gary Becker - economics in the real world -- Chapter 10: Daniel Kahneman - economic psychologist -- Index.
Sommario/riassunto	The Great Economists succinctly and accurately describes the thinking of the world's leading economic thinkers. It captures their key beliefs, explores their backgrounds, assesses their thinking and evaluates their legacy. It explains the schools of thought named after them and clearly shows how they influence our everyday lives.

2. Record Nr.	UNINA9910557553303321
Autore	García-Loureiro Antonio
Titolo	Nanowire Field-Effect Transistor (FET)
Pubbl/distr/stampa	Basel, Switzerland, : MDPI - Multidisciplinary Digital Publishing Institute, 2021
Descrizione fisica	1 online resource (96 p.)
Soggetti	History of engineering and technology
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Sommario/riassunto	In the last few years, the leading semiconductor industries have introduced multi-gate non-planar transistors into their core business. These are being applied in memories and in logical integrated circuits to achieve better integration on the chip, increased performance, and reduced energy consumption. Intense research is underway to develop these devices further and to address their limitations, in order to continue transistor scaling while further improving performance. This Special Issue looks at recent developments in the field of nanowire field-effect transistors (NW-FETs), covering different aspects of the technology, physics, and modelling of these nanoscale devices.